

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	655	(438/227).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/01 17:33
L5	4	4 and (@pd>"20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:34
L6	797	(438/458).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/01 17:34
L7	87	6 and (@pd>"20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:41
L8	1274	(438/464).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/01 17:41
L9	51	8 and (@pd>"20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:45
L10	925	(438/459).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/01 17:45
L11	91	10 and (@pd>"20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:49

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L12	108698	("438"/\$ and "257"/\$).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:49
L13	1416	12 and ((under near3 (etch\$3 remov\$3)) same (lateral\$4 side horizontal\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:53
L14	319	12 and ((under near3 (etch\$3 remov\$3)) near5 (lateral\$4 side horizontal\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 17:54

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(monolithical\$3 and semiconductor and circuit and wafer and (conductive near2 surface) and (protective near2 (layer film)) and (attachment near2 (layer film)) and (passage near2 hole) and trench and (lateral near2 under\$etch\$3)). clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/01 18:01